

IXFH26N60Q

IXFH26N60Q Information

www.heleswee.com	Part Number Manufacturer Category	IXFH26N60Q IXYS Discrete Semiconductor Products	
	Description	Transistors - FETs, MOSFETs - Single MOSFET N-CH 600V 26A TO-247AD	1.14
	Package	TO-247-3 For the pricing/inventory/lead time, please contact	
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IXFH26N60Q Specifications

Manufacturer Part Number	IXFH26N60Q
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	HiPerFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	26A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4.5V @ 4mA
Gate Charge (Qg) (Max) @ Vgs	200nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	5100pF @ 25V
Vgs (Max)	$\pm 20\mathrm{V}$
FET Feature	-
Power Dissipation (Max)	360W (Tc)
Rds On (Max) @ Id, Vgs	250 mOhm @ 13A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247AD (IXFH)
Package / Case	TO-247-3
	Report errors?

Report errors?

IXFH26N60Q Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IXFH26N60Q Payment Methods



IXFH26N60Q Shipping Methods



If you have any question about IXFH26N60Q, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com